

# 74HC2G125-Q100; 74HCT2G125-Q100

Dual buffer/line driver; 3-state

Rev. 1 — 3 April 2013

Product data sheet

## 1. General description

The 74HC2G125-Q100; 74HCT2G125-Q100 are dual buffer/line drivers with 3-state outputs controlled by the output enable inputs ( $\overline{\text{nOE}}$ ). Inputs include clamp diodes which enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$
- Input levels:
  - ◆ For 74HC2G125-Q100: CMOS level
  - ◆ For 74HCT2G125-Q100: TTL level
- Wide supply voltage range from 2.0 V to 6.0 V
- Symmetrical output impedance
- High noise immunity
- Low power consumption
- Balanced propagation delays
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200\text{ pF}$ ,  $R = 0\text{ }\Omega$ )
- Multiple package options



3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC2G125DP-Q100 74HCT2G125DP-Q100	−40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74HC2G125DC-Q100 74HCT2G125DC-Q100	−40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1

4. Marking

Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74HC2G125DP-Q100	H25
74HCT2G125DP-Q100	T25
74HC2G125DC-Q100	H25
74HCT2G125DC-Q100	T25

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

Fig 1. Logic symbol

Fig 2. IEC logic symbol

Fig 3. Logic diagram (one driver)

## 6. Pinning information

### 6.1 Pinning

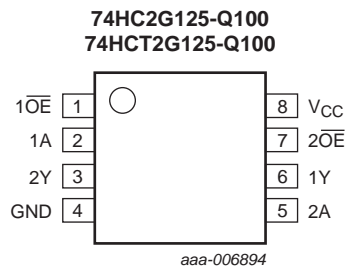


Fig 4. Pin configuration SOT505-2 (TSSOP8) and SOT765-1 (VSSOP8)

### 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
$\overline{1OE}, \overline{2OE}$	1, 7	output enable input (active LOW)
1A, 2A	2, 5	data input
GND	4	ground (0 V)
1Y, 2Y	6, 3	data output
V <sub>CC</sub>	8	supply voltage

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

Control	Input	Output
$\overline{nOE}$	nA	nY
L	L	L
L	H	H
H	X	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	[1] -	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	[1] -	±20	mA
I <sub>O</sub>	output current	V <sub>O</sub> = -0.5 V to (V <sub>CC</sub> + 0.5 V)	[1] -	35	mA
I <sub>CC</sub>	supply current		-	70	mA

**Table 5.** Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$I_{\text{GND}}$	ground current		-70	-	mA
$T_{\text{stg}}$	storage temperature		-65	+150	°C
$P_{\text{tot}}$	total power dissipation	$T_{\text{amb}} = -40\text{ °C to }+125\text{ °C}$	[2]	300	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of  $P_{\text{tot}}$  derates linearly with 2.5 mW/K.  
For VSSOP8 package: above 110 °C the value of  $P_{\text{tot}}$  derates linearly with 8 mW/K.

## 9. Recommended operating conditions

**Table 6.** Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74HC2G125-Q100			74HCT2G125-Q100			Unit
			Min	Typ	Max	Min	Typ	Max	
$V_{\text{CC}}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
$V_{\text{I}}$	input voltage		0	-	$V_{\text{CC}}$	0	-	$V_{\text{CC}}$	V
$V_{\text{O}}$	output voltage		0	-	$V_{\text{CC}}$	0	-	$V_{\text{CC}}$	V
$T_{\text{amb}}$	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{\text{CC}} = 2.0\text{ V}$	-	-	625	-	-	-	ns/V
		$V_{\text{CC}} = 4.5\text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	83	-	-	-	ns/V

## 10. Static characteristics

**Table 7.** Static characteristicsVoltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{\text{amb}} = 25\text{ °C}$ .

Symbol	Parameter	Conditions	T <sub>amb</sub> = −40 °C to +85 °C			T <sub>amb</sub> = −40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	
74HC2G125-Q100								
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		I <sub>O</sub> = −20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	V
		I <sub>O</sub> = −20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	V
		I <sub>O</sub> = −20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	V
		I <sub>O</sub> = −6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	4.32	-	3.7	-	V
		I <sub>O</sub> = −7.8 mA; V <sub>CC</sub> = 6.0 V	5.34	5.81	-	5.2	-	V

**Table 7.** Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

Symbol	Parameter	Conditions	$T_{amb} = -40\text{ }^{\circ}\text{C to } +85\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to } +125\text{ }^{\circ}\text{C}$		Unit
			Min	Typ	Max	Min	Max	
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$						
		$I_O = 20\text{ }\mu\text{A}; V_{CC} = 2.0\text{ V}$	-	0	0.1	-	0.1	V
		$I_O = 20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$	-	0	0.1	-	0.1	V
		$I_O = 20\text{ }\mu\text{A}; V_{CC} = 6.0\text{ V}$	-	0	0.1	-	0.1	V
		$I_O = 6.0\text{ mA}; V_{CC} = 4.5\text{ V}$	-	0.15	0.33	-	0.4	V
		$I_O = 7.8\text{ mA}; V_{CC} = 6.0\text{ V}$	-	0.16	0.33	-	0.4	V
$I_I$	input leakage current	$V_I = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0\text{ V}$	-	-	$\pm 1.0$	-	$\pm 1.0$	$\mu\text{A}$
$I_{OZ}$	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0\text{ V}$	-	-	$\pm 5.0$	-	$\pm 10$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC} \text{ or } \text{GND}; I_O = 0\text{ A}; V_{CC} = 6.0\text{ V}$	-	-	10	-	20	$\mu\text{A}$
$C_I$	input capacitance		-	1.0	-	-	-	pF
$C_O$	output capacitance		-	1.5	-	-	-	pF
<b>74HCT2G125-Q100</b>								
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to } 5.5\text{ V}$	2.0	1.6	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V to } 5.5\text{ V}$	-	1.2	0.8	-	0.8	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5\text{ V}$						
		$I_O = -20\text{ }\mu\text{A}$	4.4	4.5	-	4.4	-	V
		$I_O = -6.0\text{ mA}$	3.84	4.32	-	3.7	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5\text{ V}$						
		$I_O = 20\text{ }\mu\text{A}$	-	0	0.1	-	0.1	V
		$I_O = 6.0\text{ mA}$	-	0.16	0.33	-	0.4	V
$I_I$	input leakage current	$V_I = V_{CC} \text{ or } \text{GND}; V_{CC} = 5.5\text{ V}$	-	-	$\pm 1.0$	-	$\pm 1.0$	$\mu\text{A}$
$I_{OZ}$	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = V_{CC} \text{ or } \text{GND}; V_{CC} = 5.5\text{ V}$	-	-	$\pm 5.0$	-	$\pm 10$	
$I_{CC}$	supply current	$V_I = V_{CC} \text{ or } \text{GND}; I_O = 0\text{ A}; V_{CC} = 5.5\text{ V}$	-	-	10	-	20	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	per input; $V_{CC} = 4.5\text{ V to } 5.5\text{ V}; V_I = V_{CC} - 2.1\text{ V}; I_O = 0\text{ A}$	-	-	375	-	410	$\mu\text{A}$
$C_I$	input capacitance		-	1.0	-	-	-	pF
$C_O$	output capacitance		-	1.5	-	-	-	pF

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 7](#).

Symbol	Parameter	Conditions	T <sub>amb</sub> = −40 °C to +85 °C			T <sub>amb</sub> = −40 °C to +125 °C		Unit	
			Min	Typ <sup>[1]</sup>	Max	Min	Max		
74HC2G125-Q100									
t <sub>pd</sub>	propagation delay	nA to nY; see <a href="#">Figure 5</a>	<a href="#">[2]</a>						
		V <sub>CC</sub> = 2.0 V	-	35	115	-	135	ns	
		V <sub>CC</sub> = 4.5 V	-	11	23	-	27	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	10	-	-	-	ns	
		V <sub>CC</sub> = 6.0 V	-	8	20	-	23	ns	
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nY; see <a href="#">Figure 6</a>	<a href="#">[2]</a>						
		V <sub>CC</sub> = 2.0 V	-	40	115	-	135	ns	
		V <sub>CC</sub> = 4.5 V	-	11	23	-	27	ns	
		V <sub>CC</sub> = 6.0 V	-	8	20	-	23	ns	
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nY; see <a href="#">Figure 6</a>	<a href="#">[2]</a>						
		V <sub>CC</sub> = 2.0 V	-	24	125	-	150	ns	
		V <sub>CC</sub> = 4.5 V	-	12	25	-	30	ns	
		V <sub>CC</sub> = 6.0 V	-	10	21	-	26	ns	
t <sub>t</sub>	transition time	see <a href="#">Figure 5</a>	<a href="#">[2]</a>						
		V <sub>CC</sub> = 2.0 V	-	18	75	-	90	ns	
		V <sub>CC</sub> = 4.5 V	-	6	15	-	18	ns	
		V <sub>CC</sub> = 6.0 V	-	5	13	-	15	ns	
C <sub>PD</sub>	power dissipation capacitance	per buffer; V <sub>I</sub> = GND to V <sub>CC</sub>	<a href="#">[3]</a>						
		output enabled	-	11	-	-	-	pF	
		output disabled	-	1	-	-	-	pF	
74HCT2G125-Q100									
t <sub>pd</sub>	propagation delay	nA to nY; see <a href="#">Figure 5</a>	<a href="#">[2]</a>						
		V <sub>CC</sub> = 4.5 V	-	15	31	-	38	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	12	-	-	-	ns	
t <sub>en</sub>	enable time	n $\overline{\text{OE}}$ to nY; see <a href="#">Figure 6</a> ; V <sub>CC</sub> = 4.5 V	<a href="#">[2]</a>	-	15	35	-	42	ns
t <sub>dis</sub>	disable time	n $\overline{\text{OE}}$ to nY; see <a href="#">Figure 6</a> ; V <sub>CC</sub> = 4.5 V	<a href="#">[2]</a>	-	15	31	-	38	ns
t <sub>t</sub>	transition time	see <a href="#">Figure 5</a> ; V <sub>CC</sub> = 4.5 V	<a href="#">[2]</a>	-	6	15	-	18	ns

**Table 8. Dynamic characteristics ...continued**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit see [Figure 7](#).

Symbol	Parameter	Conditions	$T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
$C_{PD}$	power dissipation capacitance	per buffer; $V_I = \text{GND to } V_{CC} - 1.5\text{ V}$						
		output enabled	-	11	-	-	-	pF
		output disabled	-	1	-	-	-	pF

[1] All typical values are measured at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

$t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ .

$t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

$t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

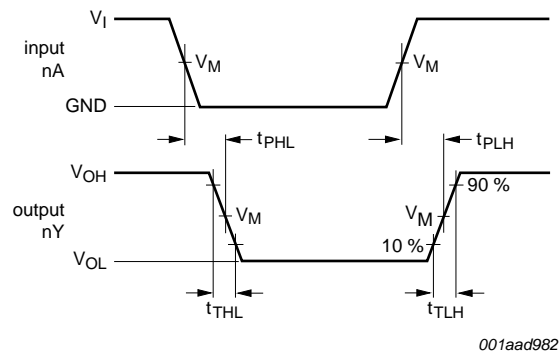
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 12. Waveforms



Measurement points are given in [Table 9](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig 5. Propagation delays data input (nA) to output (nY)**

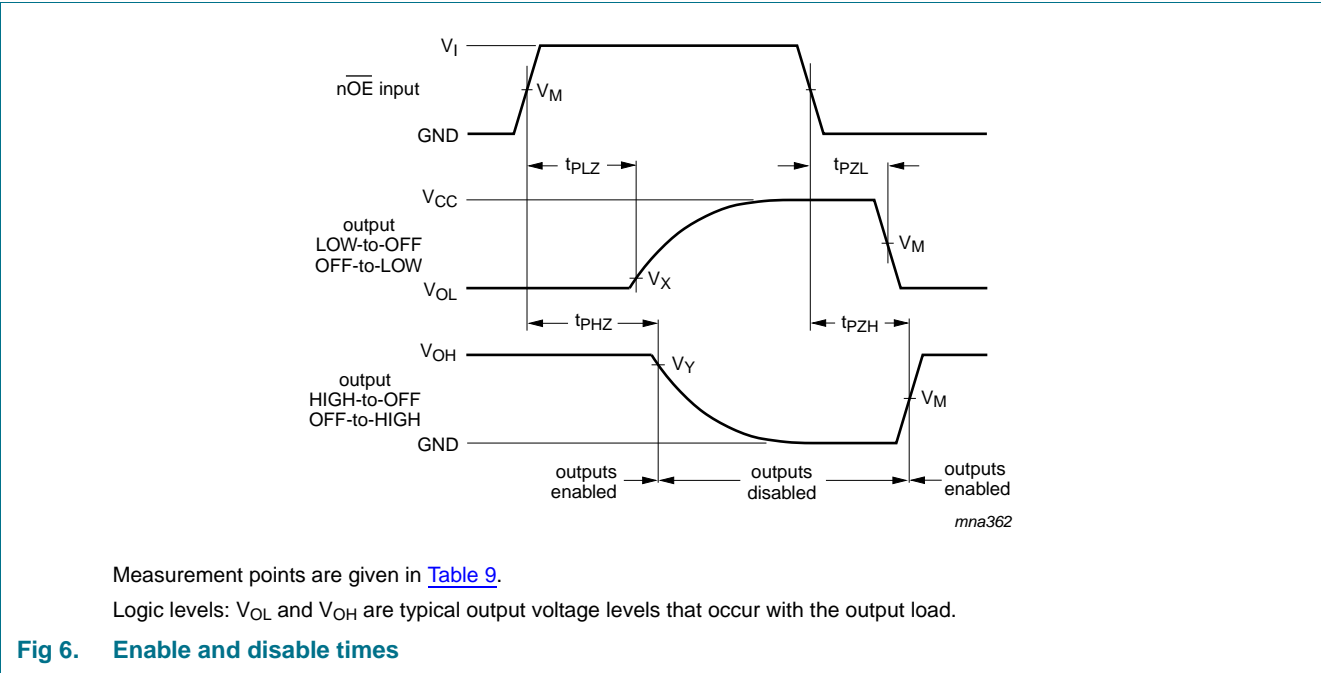


Table 9. Measurement points

Type	Input	Output		
	$V_M$	$V_M$	$V_X$	$V_Y$
74HC2G125-Q100	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.3\text{ V}$	$V_{OH} - 0.3\text{ V}$
74HCT2G125-Q100	1.3 V	1.3 V	$V_{OL} + 0.3\text{ V}$	$V_{OH} - 0.3\text{ V}$



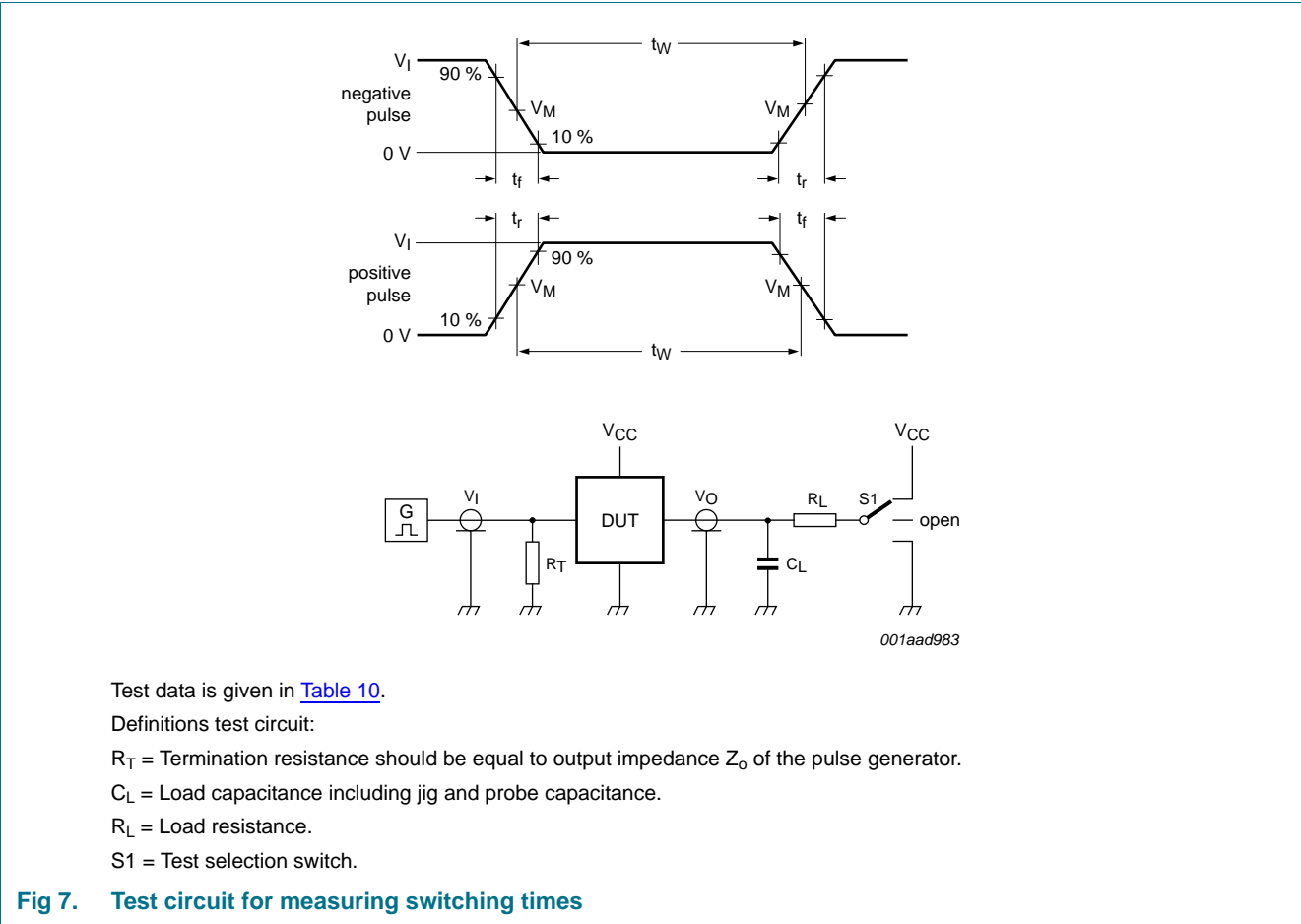


Table 10. Test data

Type	Input		Load		S1 position		
	$V_I$	$t_r, t_f$	$C_L$	$R_L$	$t_{PHL}, t_{PLH}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
74HC2G125-Q100	$V_{CC}$	$\leq 6\text{ ns}$	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$
74HCT2G125-Q100	3 V	$\leq 6\text{ ns}$	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$

13. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2

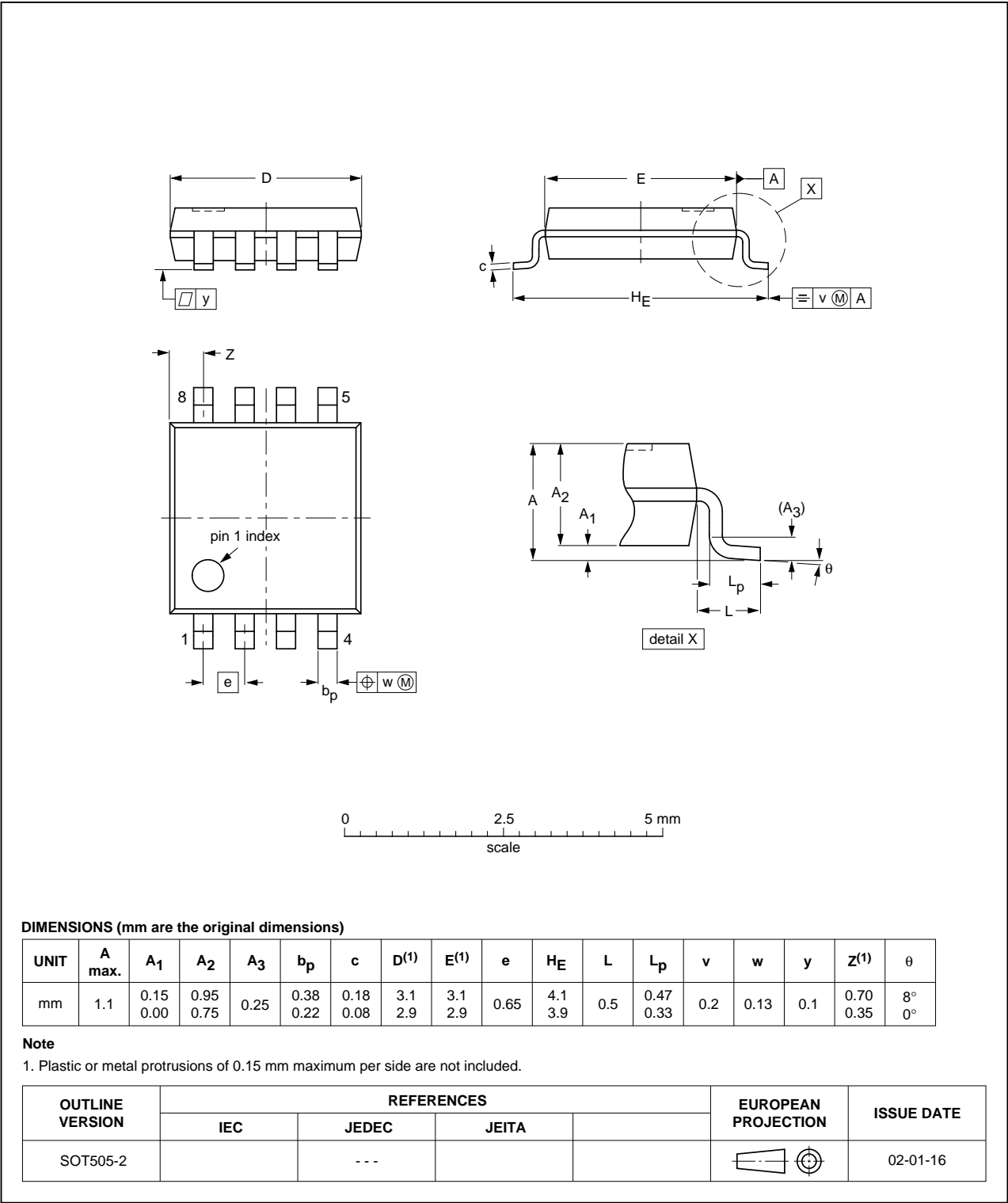


Fig 8. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

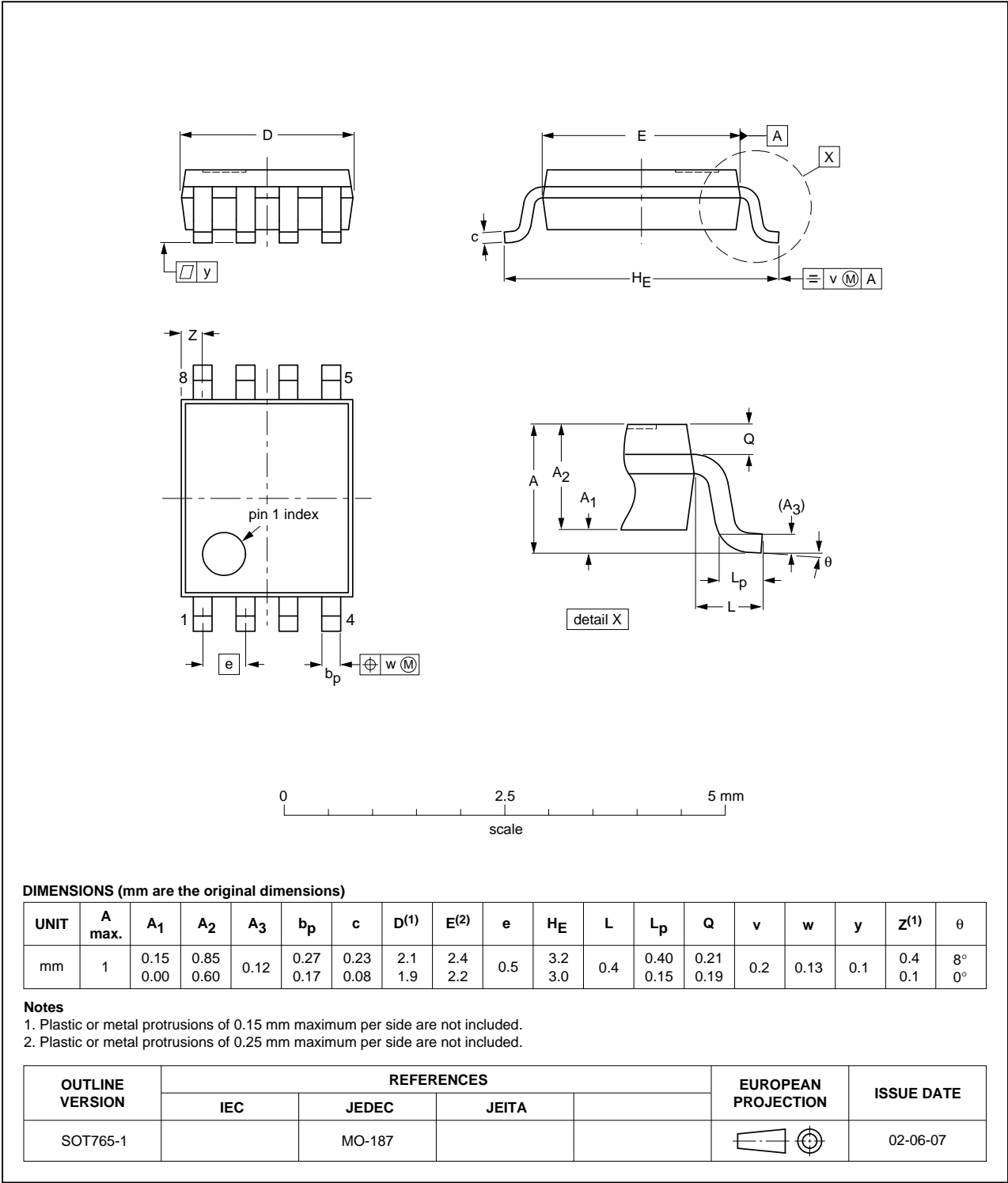


Fig 9. Package outline SOT765-1 (VSSOP8)

## 14. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model

## 15. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT2G125_Q100 v.1	20130403	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## 18. Contents

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<b>1</b>	<b>General description</b> .....	<b>1</b>
<b>2</b>	<b>Features and benefits</b> .....	<b>1</b>
<b>3</b>	<b>Ordering information</b> .....	<b>2</b>
<b>4</b>	<b>Marking</b> .....	<b>2</b>
<b>5</b>	<b>Functional diagram</b> .....	<b>2</b>
<b>6</b>	<b>Pinning information</b> .....	<b>3</b>
6.1	Pinning .....	3
6.2	Pin description .....	3
<b>7</b>	<b>Functional description</b> .....	<b>3</b>
<b>8</b>	<b>Limiting values</b> .....	<b>3</b>
<b>9</b>	<b>Recommended operating conditions</b> .....	<b>4</b>
<b>10</b>	<b>Static characteristics</b> .....	<b>4</b>
<b>11</b>	<b>Dynamic characteristics</b> .....	<b>6</b>
<b>12</b>	<b>Waveforms</b> .....	<b>7</b>
<b>13</b>	<b>Package outline</b> .....	<b>10</b>
<b>14</b>	<b>Abbreviations</b> .....	<b>12</b>
<b>15</b>	<b>Revision history</b> .....	<b>12</b>
<b>16</b>	<b>Legal information</b> .....	<b>13</b>
16.1	Data sheet status .....	13
16.2	Definitions .....	13
16.3	Disclaimers .....	13
16.4	Trademarks .....	14
<b>17</b>	<b>Contact information</b> .....	<b>14</b>
<b>18</b>	<b>Contents</b> .....	<b>15</b>

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